

L-513HDT BRIGHT RED

L-513GDT GREEN

L-513IDT HIGH EFFICIENCY RED

L-513EDT ORANGE

L-513SGDT SUPER BRIGHT GREEN

L-513YDT YELLOW

Features

- LOW POWER CONSUMPTION.
- RELIABLE AND RUGGED.
- EXCELLENT UNIFORMITY OF LIGHT OUTPUT.
- SUITABLE FOR LEVEL INDICATOR.
- I.C. COMPATIBLE.
- LONG LIFE - SOLID STATE RELIABILITY.

Description

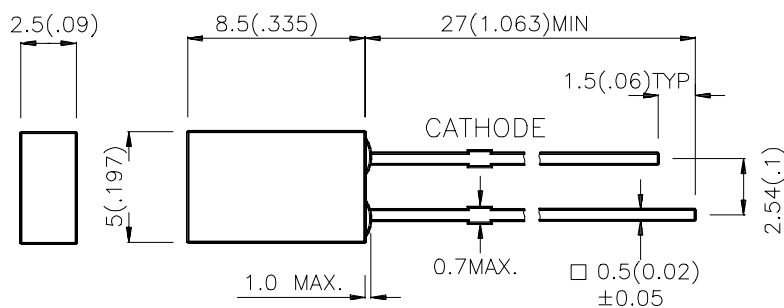
The Bright Red source color devices are made with Gallium Phosphide Red Light Emitting Diode.

The High Efficiency Red and Orange source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

The Green and Super Bright Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 10 mA *20mA		Viewing Angle
			Min.	Typ.	
L-513HDT	BRIGHT RED (GaP)	RED DIFFUSED	0.5	1	110°
L-513IDT	HIGH EFFICIENCY RED (GaAsP/GaP)	RED DIFFUSED	3	5	110°
L-513EDT	ORANGE (GaAsP/GaP)	ORANGE DIFFUSED	3	5	110°
L-513GDT	GREEN (GaP)	GREEN DIFFUSED	2	3	110°
L-513YDT	YELLOW (GaAsP/GaP)	YELLOW DIFFUSED	2	3	110°
L-513SGDT	SUPER BRIGHT GREEN (GaP)	GREEN DIFFUSED	*8	*10	110°

Notes:

1. $\theta 1/2$ is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 20mA.

Electrical / Optical Characteristics at T_A=25°C

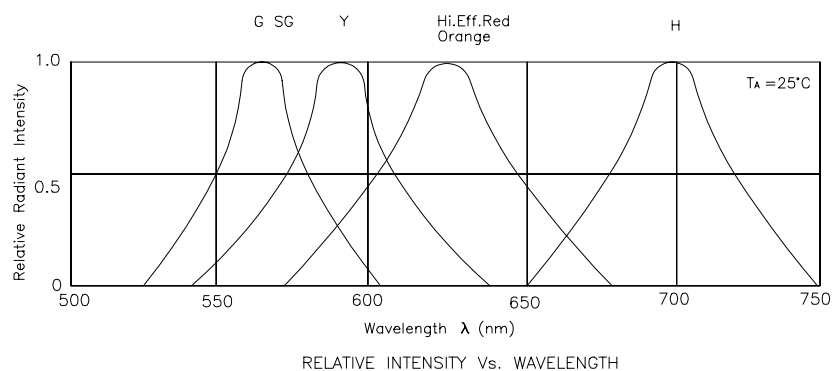
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Bright Red High Efficiency Red Orange Green Yellow Super Bright Green	700 627 627 565 590 565		nm	IF=20mA
λ_D	Dominate Wavelength	Bright Red High Efficiency Red Orange Green Yellow Super Bright Green	660 625 625 568 588 568		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Halfwidth	Bright Red High Efficiency Red Orange Green Yellow Super Bright Green	45 45 45 30 35 30		nm	IF=20mA
C	Capacitance	Bright Red High Efficiency Red Orange Green Yellow Super Bright Green	40 15 15 15 20 15		pF	VF=0V;f=1MHz
V _F	Forward Voltage	Bright Red High Efficiency Red Orange Green Yellow Super Bright Green	2.25 2.0 2.0 2.2 2.1 2.2	2.5 2.5 2.5 2.5 2.5 2.5	V	IF=20mA
I _R	Reverse Current	All		10	uA	VR = 5V

Absolute Maximum Ratings at $T_A=25^\circ\text{C}$

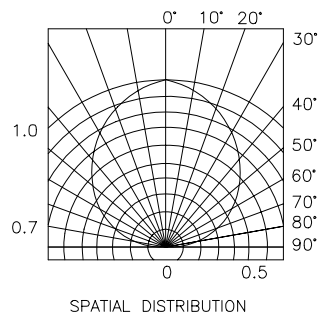
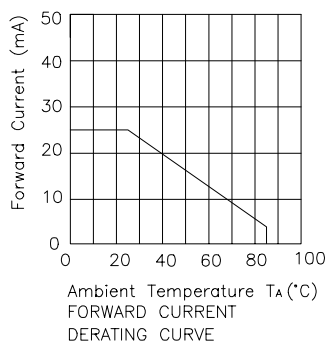
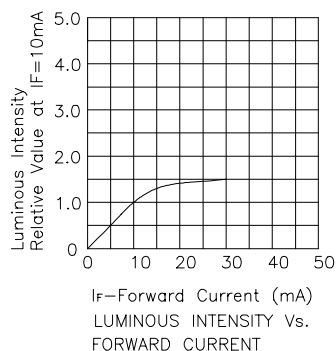
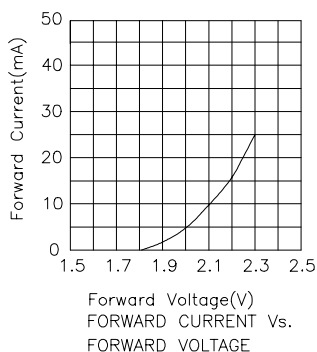
Parameter	Bright Red	High Efficiency Red	Orange	Green	Yellow	Super Bright Green	Units
Power dissipation	120	105	105	105	105	105	mW
DC Forward Current	25	30	30	25	30	25	mA
Peak Forward Current [1]	120	160	160	140	140	140	mA
Reverse Voltage	5	5	5	5	5	5	V
Operating/Storage Temperature	-40°C To $+85^\circ\text{C}$						
Lead Solder Temperature [2]	260°C For 5 Seconds						

Notes:

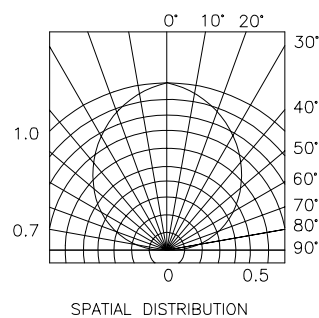
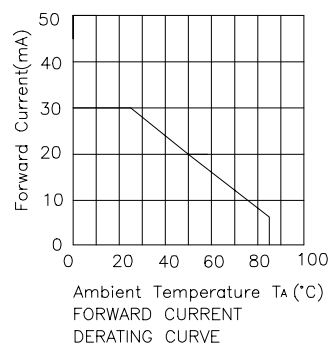
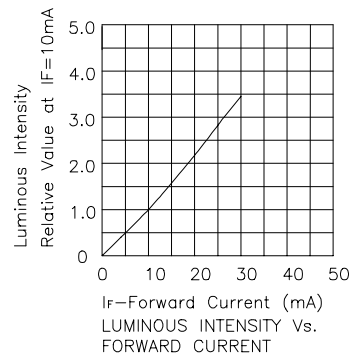
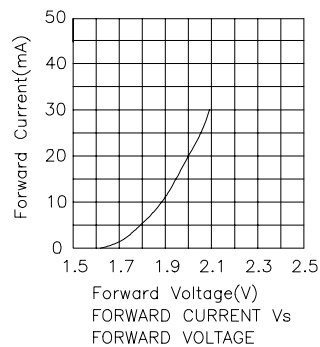
- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 4mm below package base.



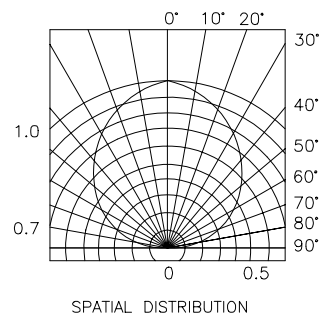
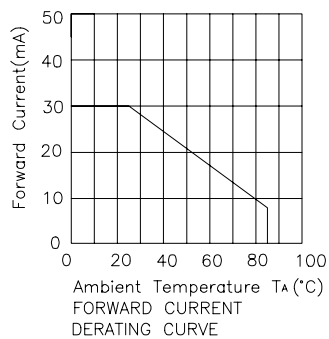
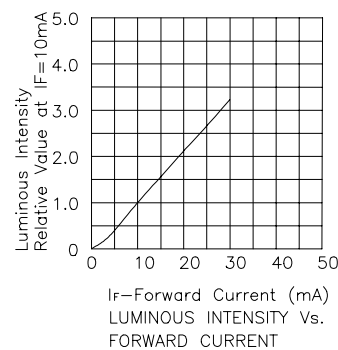
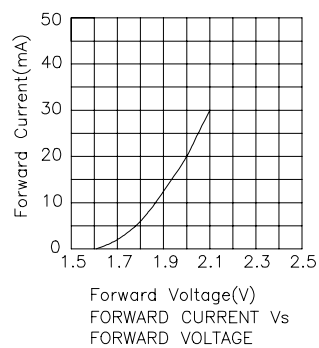
Bright Red L-513HDT



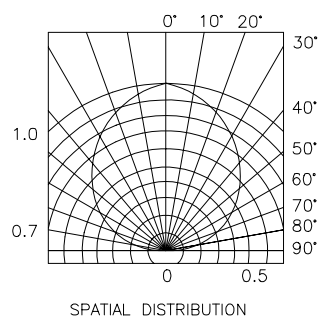
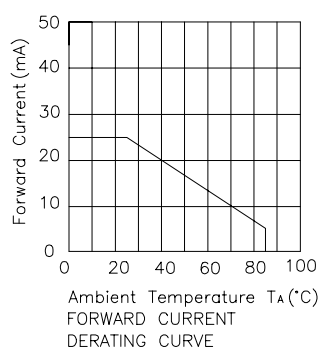
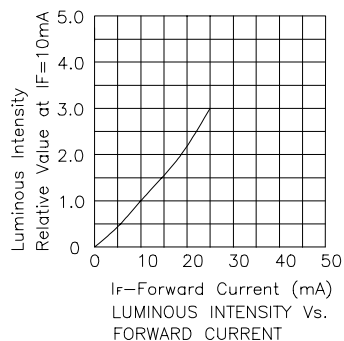
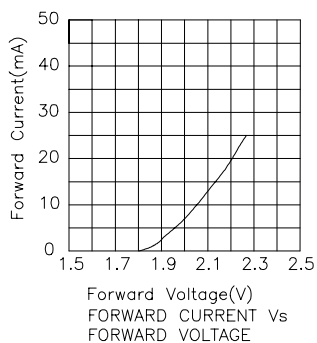
High Efficiency Red L-513IDT



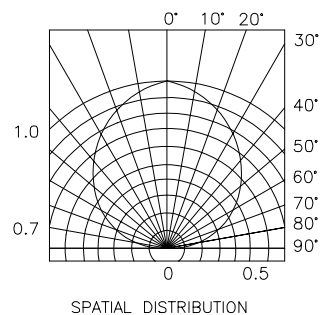
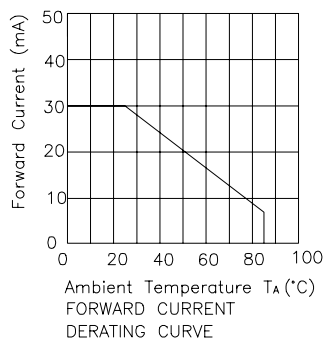
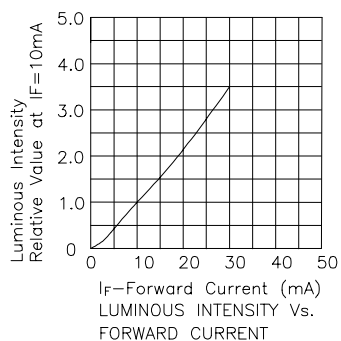
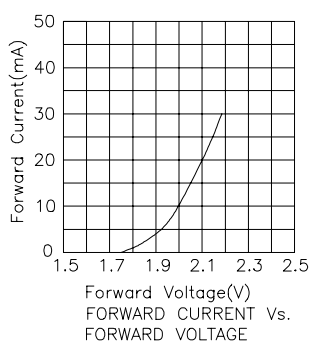
Orange L-513EDT



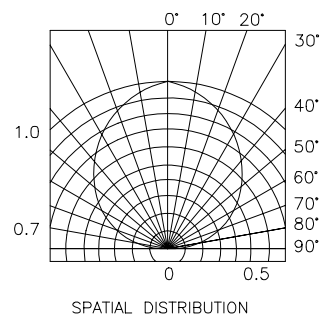
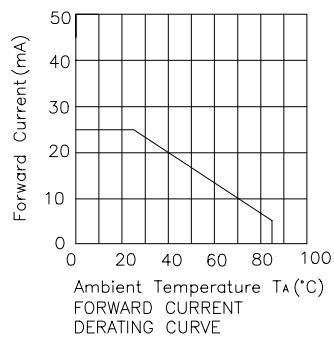
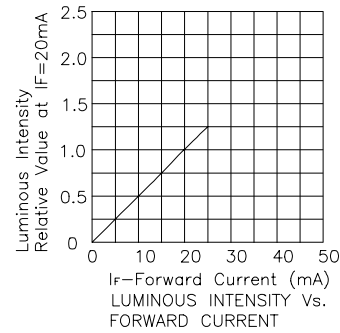
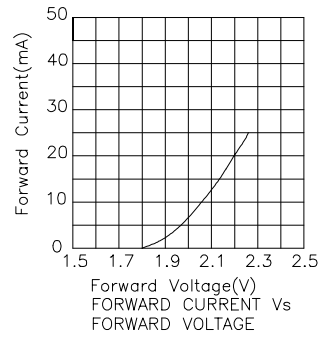
Green L-513GDT



Yellow L-513YDT



Super Bright Green L-513SGDT



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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